

Improving DRAM Performance by Parallelizing Refreshes with Accesses

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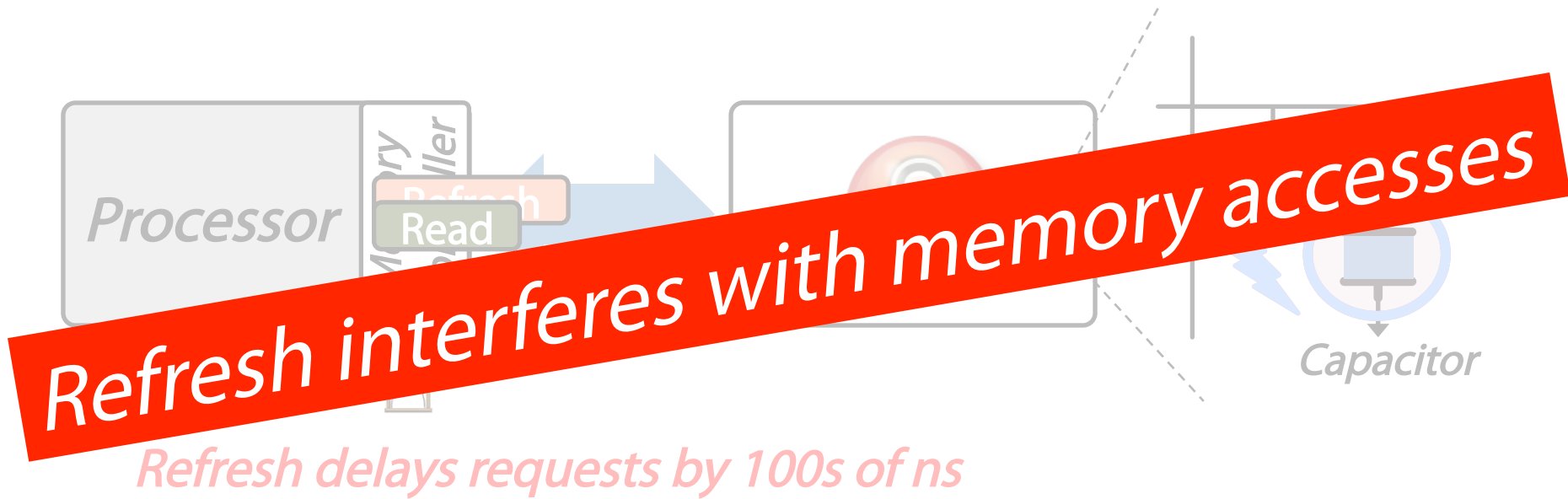
Executive Summary

- DRAM refresh interferes with memory accesses
 - Degrades system performance and energy efficiency
 - Becomes exacerbated as DRAM density increases
- Goal: Serve memory accesses in parallel with refreshes to reduce refresh interference on demand requests
- Our mechanisms:
 - 1. Enable more parallelization between refreshes and accesses across different banks with **new per-bank refresh scheduling algorithms**
 - 2. Enable serving accesses concurrently with refreshes in the same bank by **exploiting DRAM subarrays**
- Improve system performance and energy efficiency for a wide variety of different workloads and DRAM densities
 - 20.2% and 9.0% for 8-core systems using 32Gb DRAM
 - Very close to the ideal scheme without refreshes

Outline

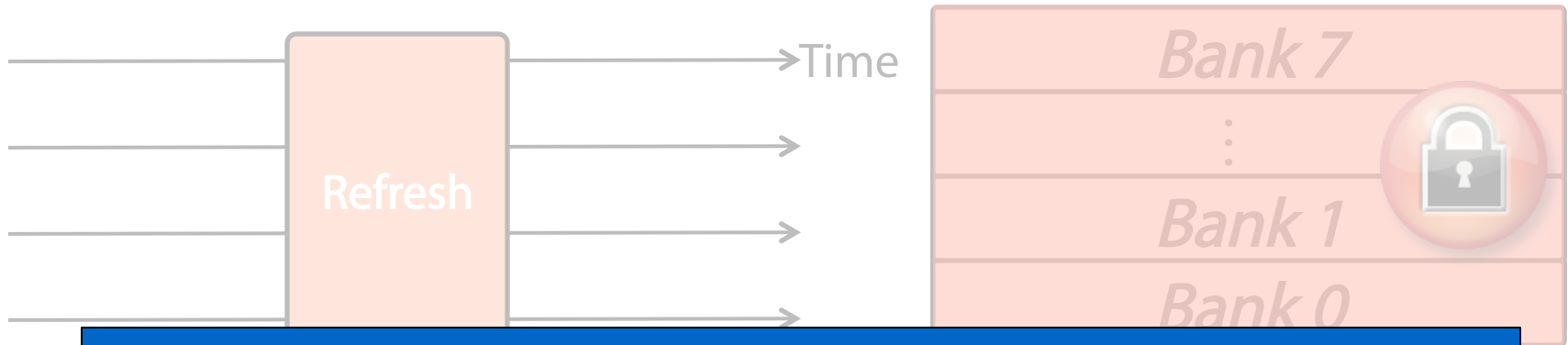
- **Motivation and Key Ideas**
- DRAM and Refresh Background
- Our Mechanisms
- Results

Refresh Penalty

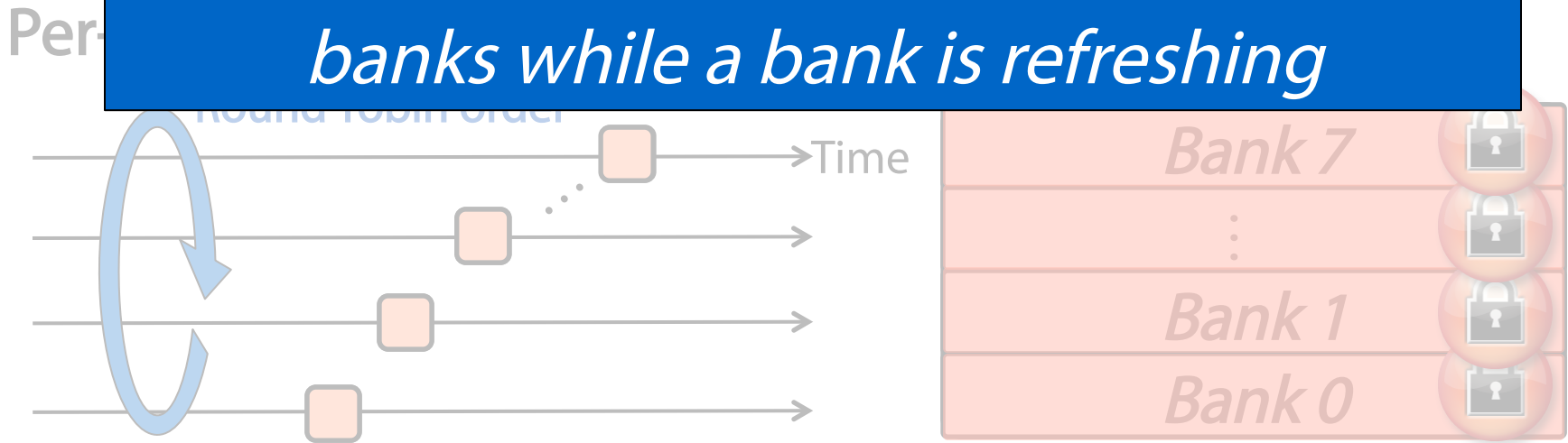


Existing Refresh Modes

All-bank refresh in commodity DRAM (DDR_x)



Per-bank refresh allows accesses to other banks while a bank is refreshing

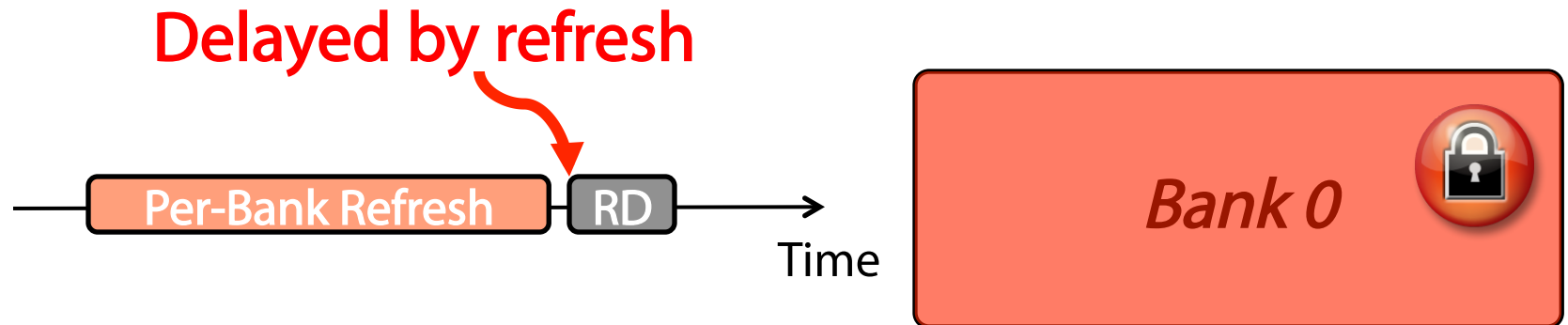


Shortcomings of Per-Bank Refresh

- Problem 1: Refreshes to different banks are scheduled in a **strict round-robin order**
 - The static ordering is hardwired into DRAM chips
 - Refreshes busy banks with many queued requests when other banks are idle
- Key idea: Schedule per-bank refreshes to idle banks opportunistically in a dynamic order

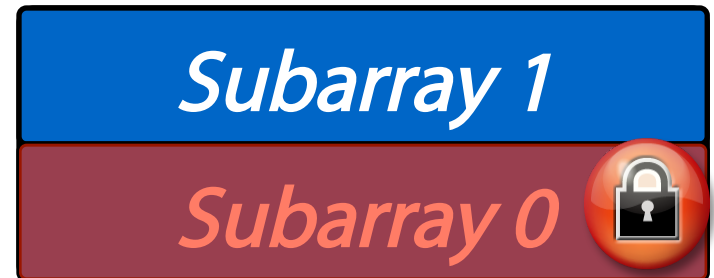
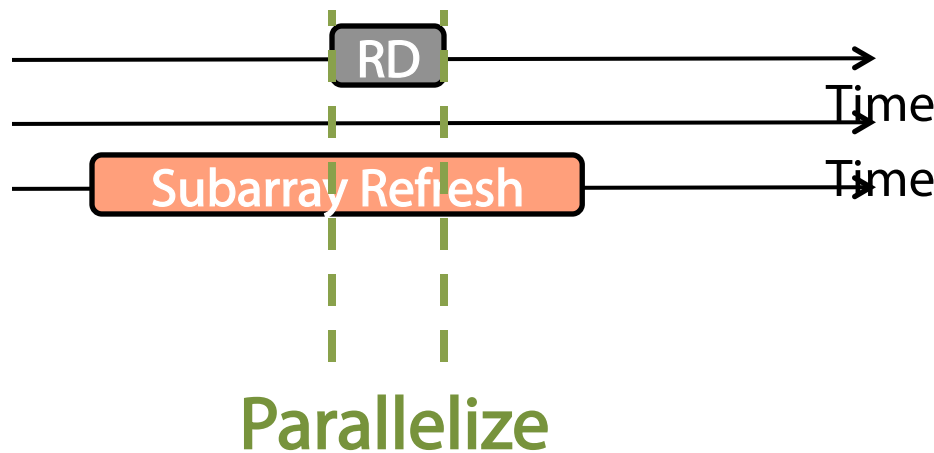
Shortcomings of Per-Bank Refresh

- Problem 2: Banks that are being refreshed cannot concurrently serve memory requests



Shortcomings of Per-Bank Refresh

- Problem 2: Refreshing banks cannot concurrently serve memory requests
- Key idea: Exploit **subarrays** within a bank to parallelize refreshes and accesses across subarrays



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DRAM System Organization

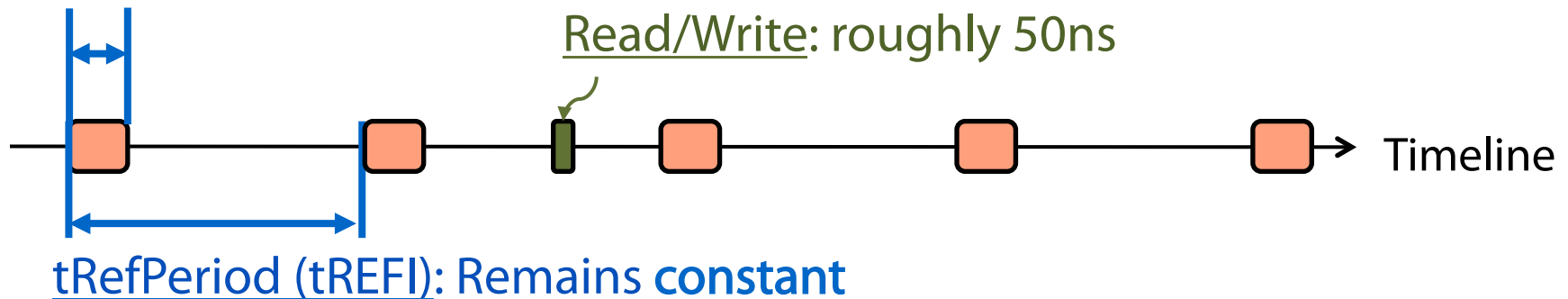


- Banks can serve multiple requests in parallel

DRAM Refresh Frequency

- DRAM standard requires memory controllers to send periodic refreshes to DRAM

tRefLatency (tRFC): Varies based on DRAM chip density (e.g., 350ns)

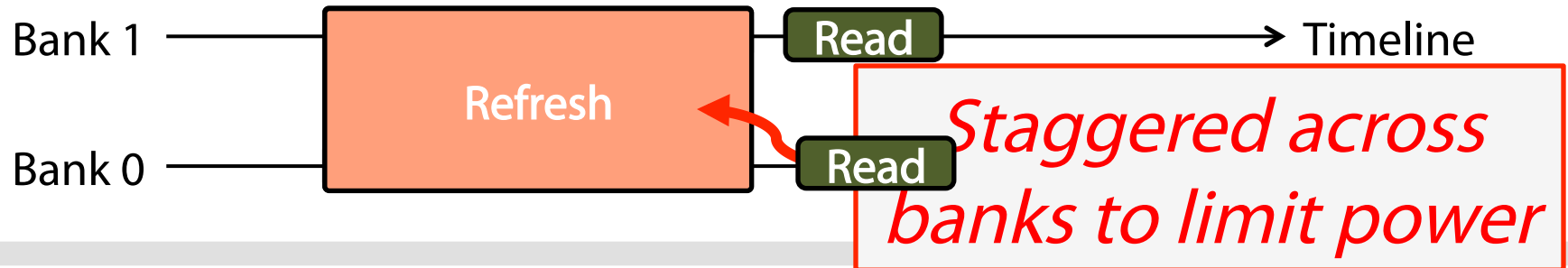


Increasing Performance Impact

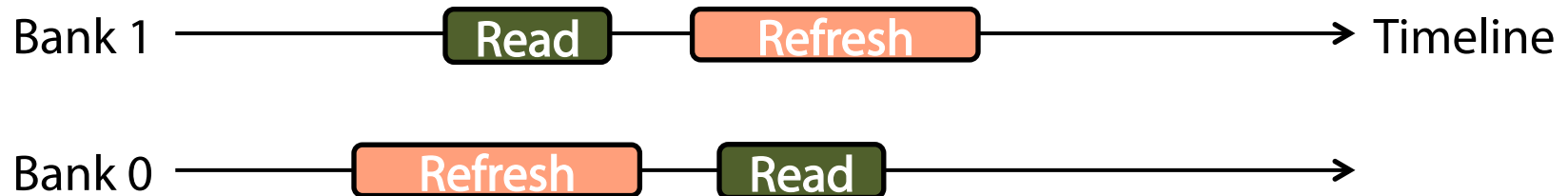
- DRAM is **unavailable to serve requests** for $\frac{t_{RefLatency}}{t_{RefPeriod}}$ of time
- **6.7%** for today's 4Gb DRAM
- **Unavailability** increases with higher density due to higher $t_{RefLatency}$
 - **23% / 41%** for future 32Gb / 64Gb DRAM

All-Bank vs. Per-Bank Refresh

All-Bank Refresh: Employed in commodity DRAM (DDR_x, LPDDR_x)



Per-Bank Refresh: In mobile DRAM (LPDDR_x)



Can serve memory accesses in parallel with refreshes across banks

Shortcomings of Per-Bank Refresh

- 1) Per-bank refreshes are **strictly scheduled** in round-robin order (as fixed by DRAM's internal logic)
- 2) A **refreshing bank** cannot serve memory accesses

Goal: Enable more parallelization between refreshes and accesses using practical mechanisms

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 - 2. Subarray Access-Refresh Parallelization (SARP)
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Our First Approach: DARP

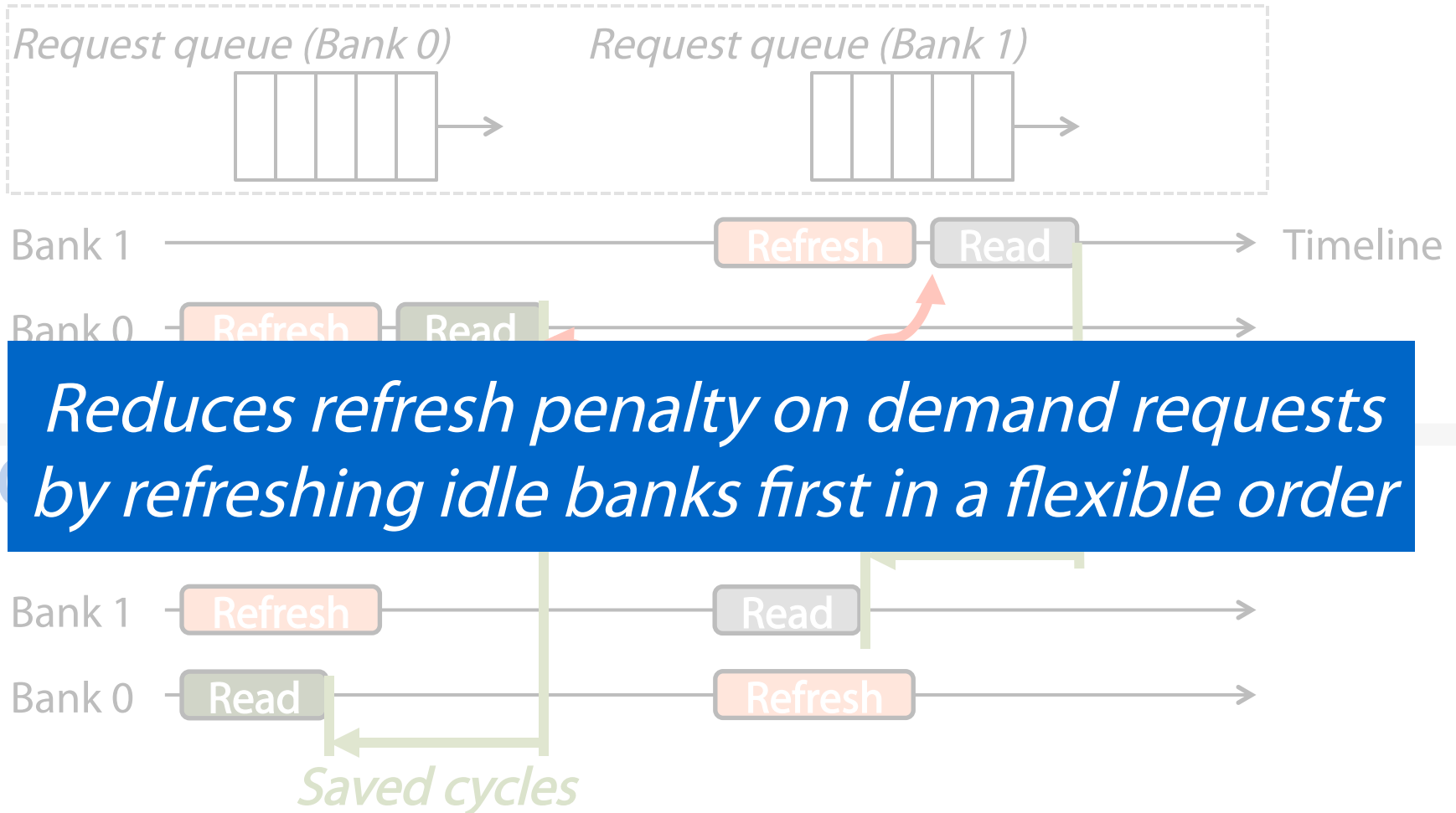
- **Dynamic Access-Refresh Parallelization (DARP)**
 - An improved scheduling policy for **per-bank refreshes**
 - Exploits **refresh scheduling flexibility** in DDR DRAM
- **Component 1: Out-of-order per-bank refresh**
 - Avoids poor static scheduling decisions
 - Dynamically issues per-bank refreshes to idle banks
- **Component 2: Write-Refresh Parallelization**
 - Avoids refresh interference on latency-critical reads
 - Parallelizes refreshes with a **batch of writes**

1) Out-of-Order Per-Bank Refresh

- Dynamic scheduling policy that prioritizes refreshes to idle banks
- Memory controllers decide which bank to refresh

1) Out-of-Order Per-Bank Refresh

Baseline: Round robin

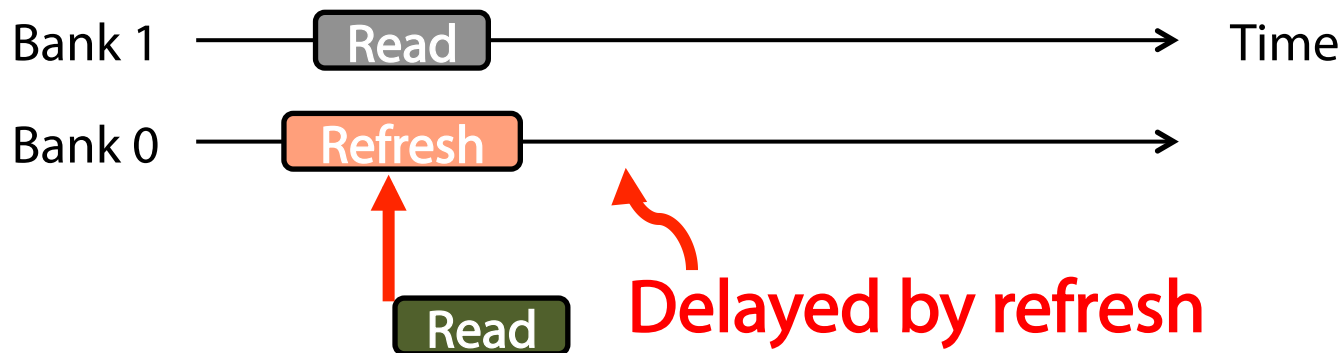


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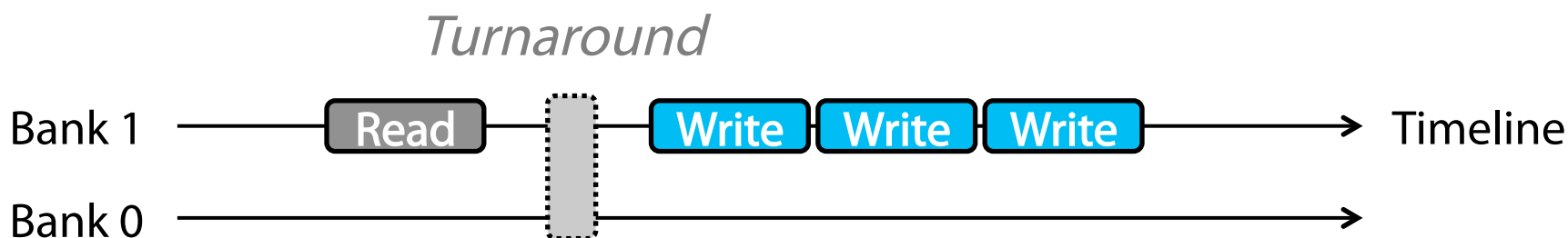
Refresh Interference on Upcoming Requests

- Problem: A refresh may collide with an upcoming request in the near future



DRAM Write Draining

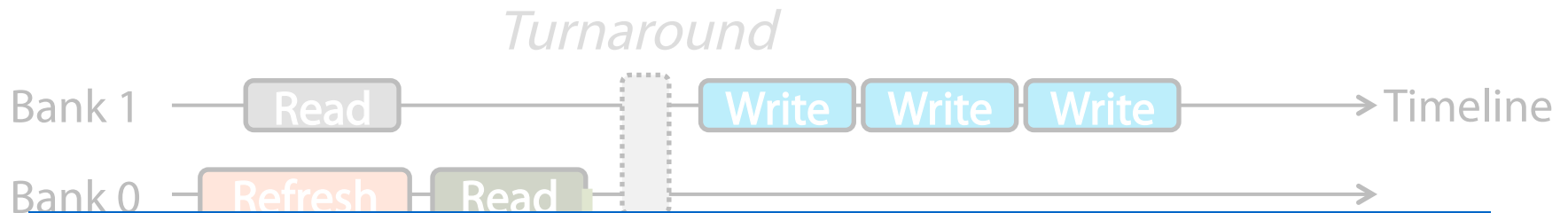
- Observations:
- 1) **Bus-turnaround latency** when transitioning from writes to reads or vice versa
 - To mitigate **bus-turnaround latency**, writes are typically drained to DRAM in a batch during a period of time
- 2) Writes are not **latency-critical**



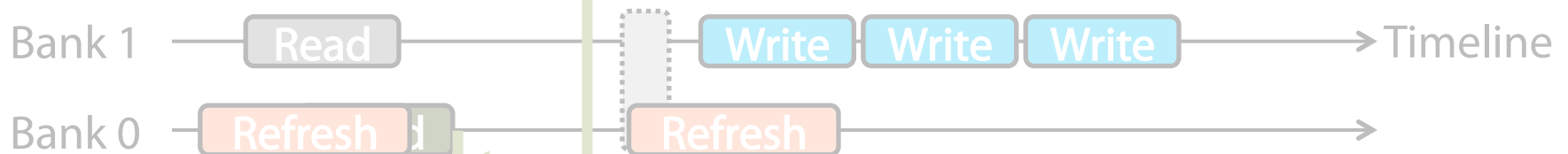
2) Write-Refresh Parallelization

- Proactively schedules refreshes when banks are serving write batches

Baseline



Avoids stalling latency-critical read requests by refreshing with non-latency-critical writes



1. Postpone refresh Refresh during writes

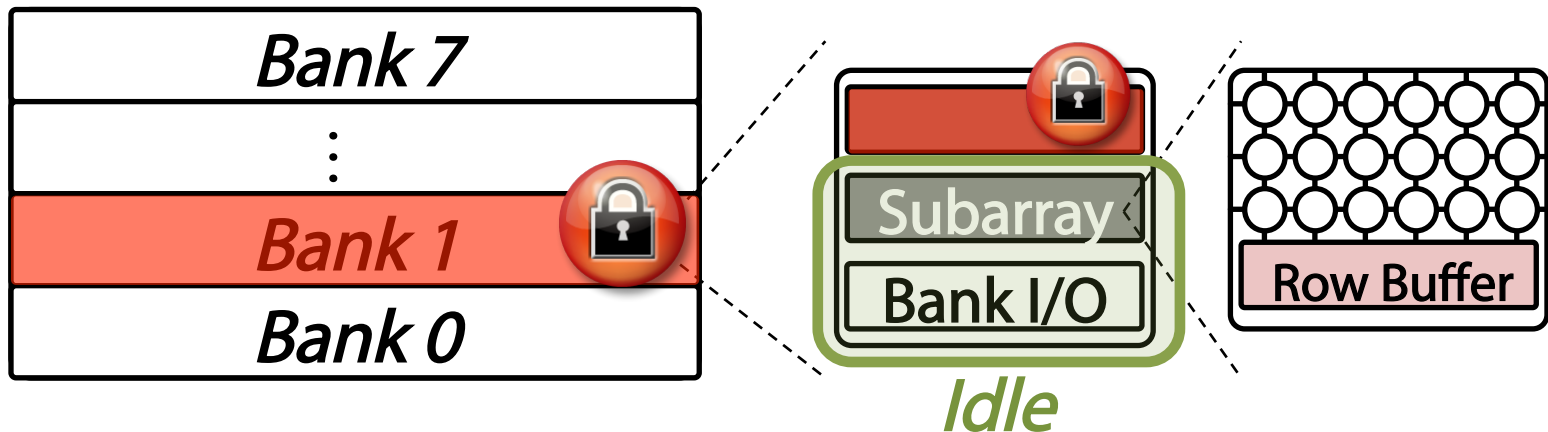
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Our Second Approach: SARP

Observations:

1. A bank is further divided into **subarrays**
 - Each has its own **row buffer** to perform refresh operations



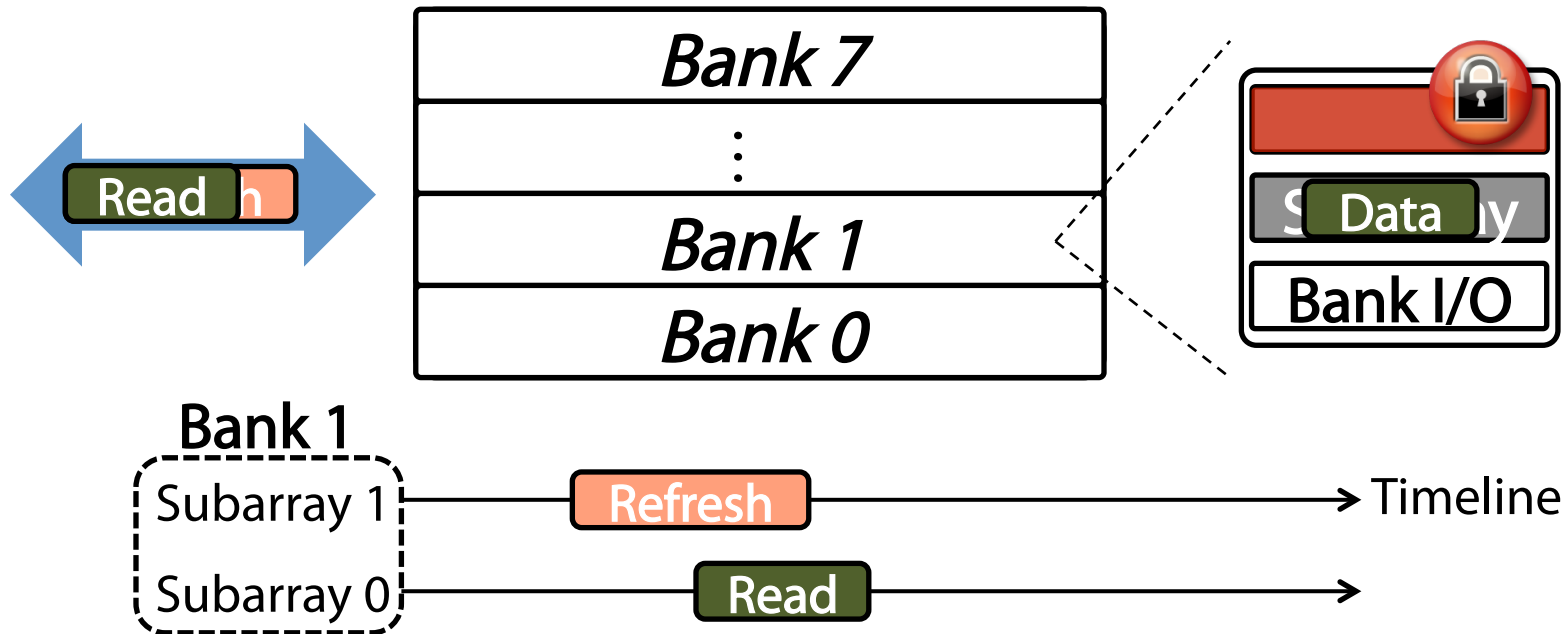
2. Some **subarrays** and **bank I/O** remain completely **idle** during refresh

Our Second Approach: SARP

- Subarray Access-Refresh Parallelization (SARP):
 - Parallelizes refreshes and accesses within a bank

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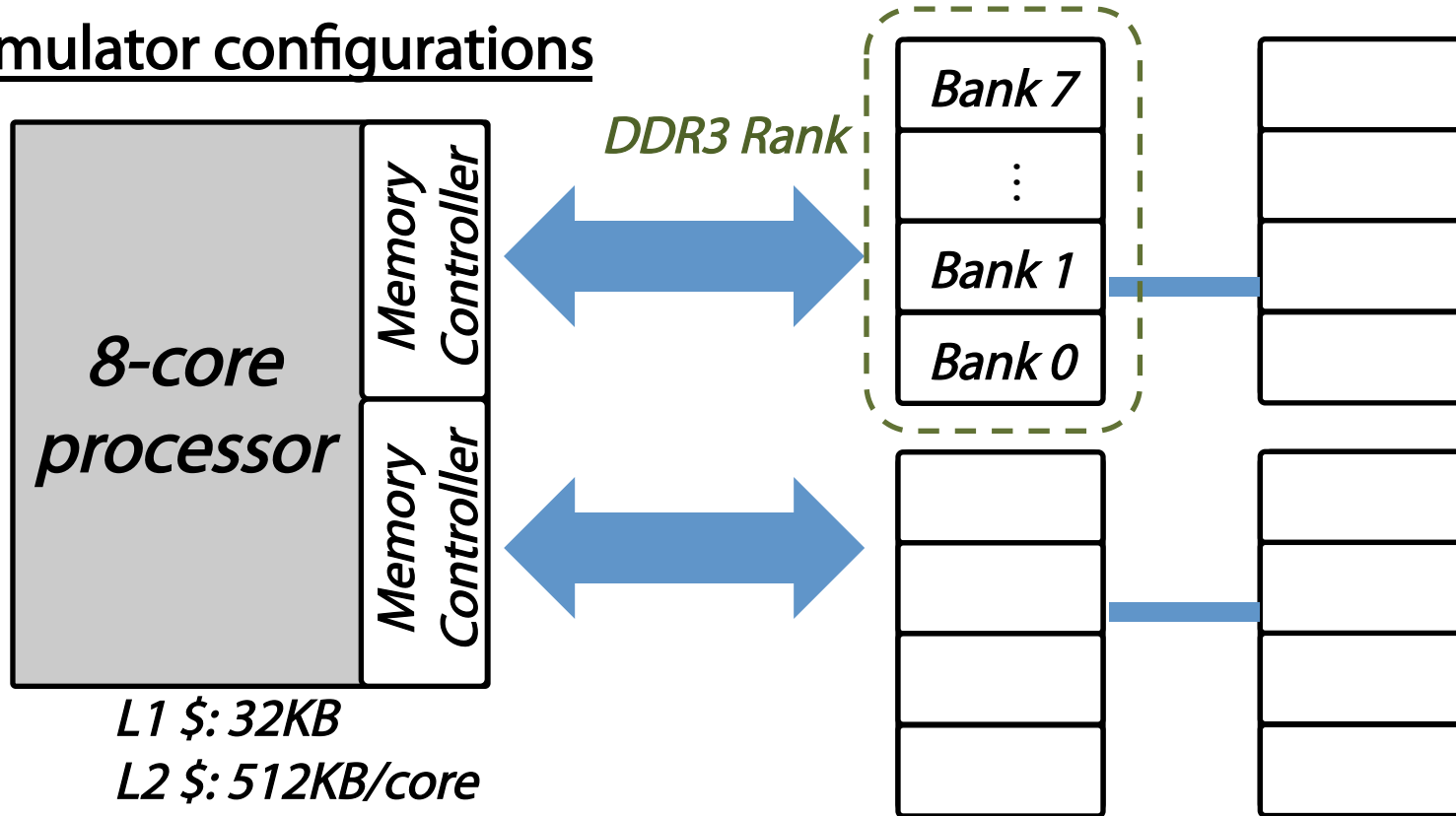
*Very modest DRAM modifications: 0.71%
die area overhead*

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Methodology

Simulator configurations

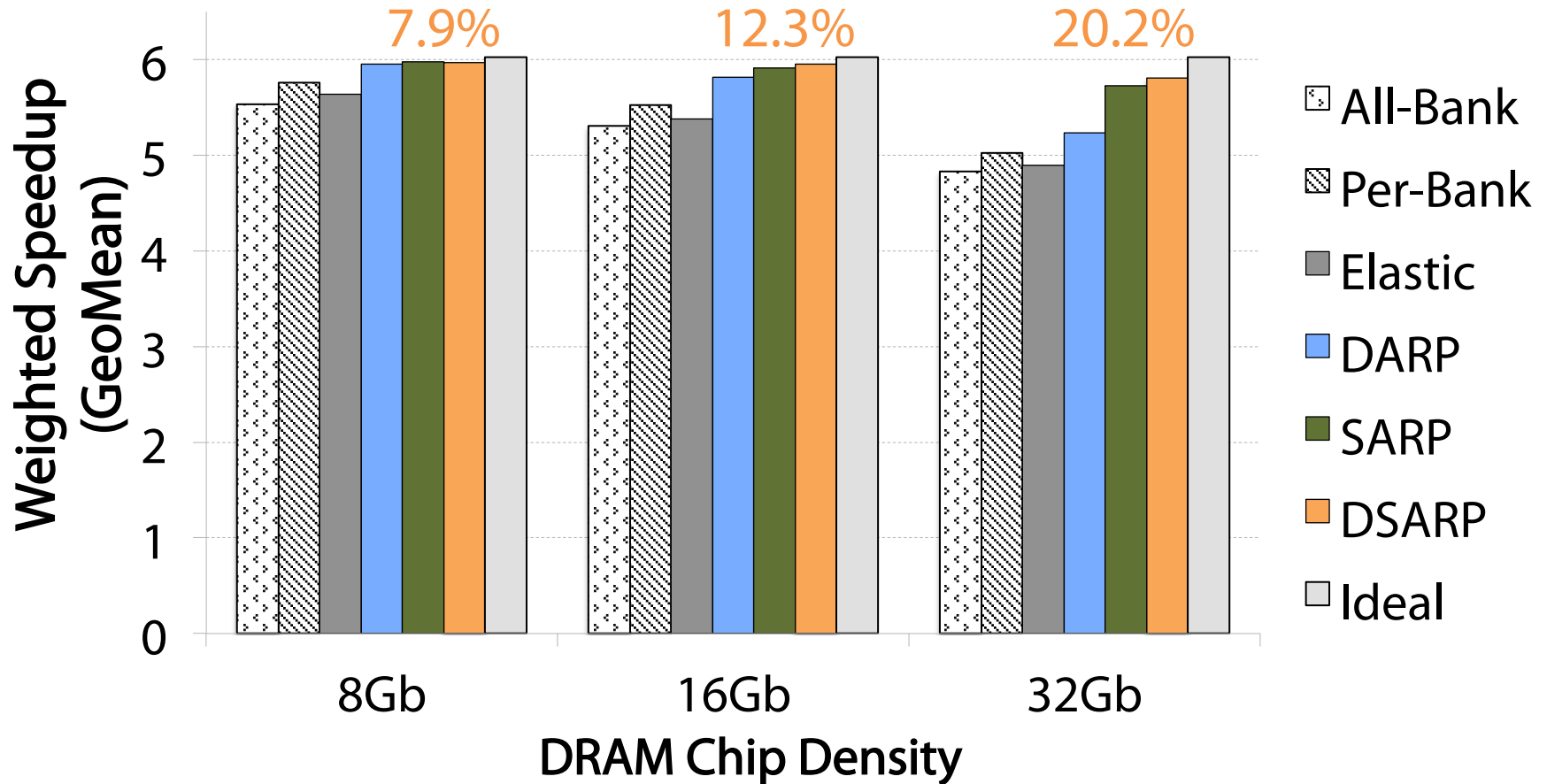


- 100 workloads: SPEC CPU2006, STREAM, TPC-C/H, random access
- System performance metric: *Weighted speedup*

Comparison Points

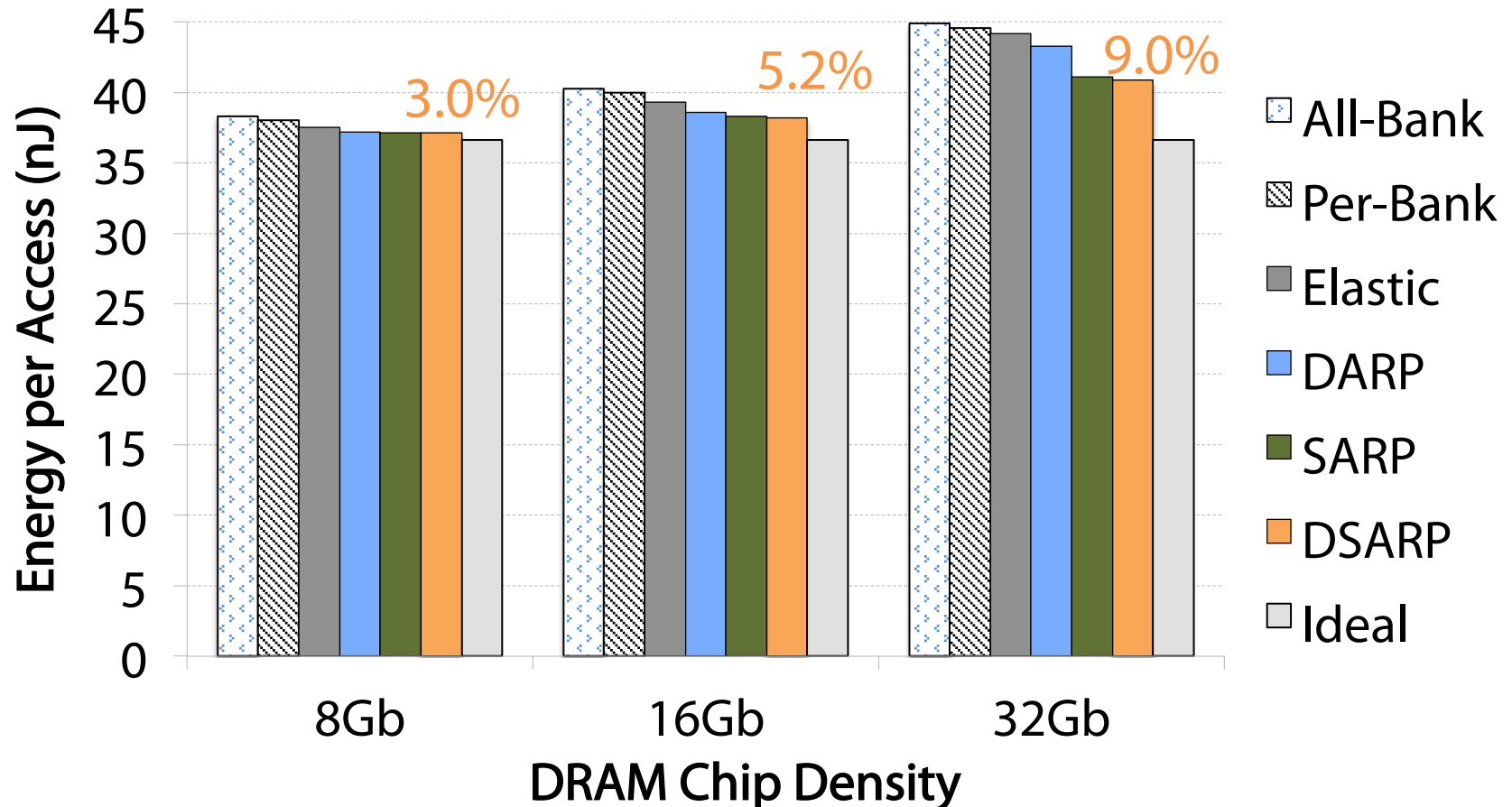
- All-bank refresh [DDR3, LPDDR3, ...]
- Per-bank refresh [LPDDR3]
- Elastic refresh [Stuecheli et al., MICRO '10]:
 - Postpones refreshes by a time delay based on the predicted rank idle time to avoid interference on memory requests
 - Proposed to schedule all-bank refreshes without exploiting per-bank refreshes
 - Cannot parallelize refreshes and accesses within a rank
- Ideal (no refresh)

System Performance



2. Consistent system performance improvement across DRAM densities (within 0.9%, 1.2%, and 3.8% of ideal)

Energy Efficiency



Consistent reduction on energy consumption

Other Results and Discussion in the Paper

- Detailed multi-core results and analysis
- Result breakdown based on memory intensity
- Sensitivity results on number of cores, subarray counts, refresh interval length, and DRAM parameters
- Comparisons to DDR4 fine granularity refresh

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